

L Number	Hits	Search Text	DB	Time stamp
1	2338	(372/27,45).CCLS.	USPAT; US-PGPUB	2003/03/23 17:43
4	146	((372/27,45).CCLS.) and ((active quantum) with polarization)	USPAT; EPO; JPO; IBM_TDB	2003/03/23 18:38
9	5	(((372/27,45).CCLS.) and ((active quantum) with polarization)) and reverse with bias with junction	USPAT; EPO; JPO; IBM_TDB	2003/03/23 18:48
14	73	((372/27,45).CCLS.) and reverse with bias with junction	USPAT; EPO; JPO; IBM_TDB	2003/03/23 18:49
19	9	(((372/27,45).CCLS.) and reverse with bias with junction) and polarization	USPAT; EPO; JPO; IBM_TDB	2003/03/23 18:49

L Number	Hits	Search Text	DB	Time stamp
1	2338	(372/27,45).CCLS.	USPAT; US-PGPUB	2003/03/23 17:43
4	146	((372/27,45).CCLS.) and ((active quantum) with polarization)	USPAT; EPO; JPO; IBM_TDB	2003/03/23 18:38
9	5	((((372/27,45).CCLS.) and ((active quantum) with polarization)) and reverse with bias with junction	USPAT; EPO; JPO; IBM_TDB	2003/03/23 18:48
14	73	((372/27,45).CCLS.) and reverse with bias with junction	USPAT; EPO; JPO; IBM_TDB	2003/03/23 18:49
19	9	((((372/27,45).CCLS.) and reverse with bias with junction) and polarization	USPAT; EPO; JPO; IBM_TDB	2003/03/23 19:19
24	2	((("5079774") or ("6369403")).PN.	USPAT; EPO; JPO; IBM_TDB	2003/03/23 19:19
29	2	((("5079774") or ("6369403")).PN.) and reverse	USPAT; EPO; JPO; IBM_TDB	2003/03/23 19:19
34	1	((("5079774") or ("6369403")).PN.) and tunnel	USPAT; EPO; JPO; IBM_TDB	2003/03/23 19:20
39	1	((("5079774") or ("6369403")).PN.) and tunnel) and reverse	USPAT; EPO; JPO; IBM_TDB	2003/03/23 19:47
44	0	GaN same substrate same (wurtzite near3 axis)	USPAT; EPO; JPO; IBM_TDB	2003/03/23 19:49
49	680	wurtzite	USPAT; EPO; JPO; IBM_TDB	2003/03/23 19:49
54	349	wurtzite and wurtzite with (crystal axis GaN)	USPAT; EPO; JPO; IBM_TDB	2003/03/23 19:50
59	67	(wurtzite and wurtzite with (crystal axis GaN)) and semiconductor near2 laser	USPAT; EPO; JPO; IBM_TDB	2003/03/23 19:58
64	40	((wurtzite and wurtzite with (crystal axis GaN)) and semiconductor near2 laser) and GaN same wurtzite	USPAT; EPO; JPO; IBM_TDB	2003/03/23 20:25
69	11	((((wurtzite and wurtzite with (crystal axis GaN)) and semiconductor near2 laser) and GaN same wurtzite) and (reverse inverted)	USPAT; EPO; JPO; IBM_TDB	2003/03/23 20:25